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Stocking Distributor

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Diodes Incorporated DMN4020LFDE-13

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>







DMN4020LFDE

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	l _D max T _A = +25°C
	20mΩ@ V _{GS} = 10V	8.0A
40V	28mΩ @ V _{GS} = 4.5V	6.7A

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions

Features and Benefits

- 0.6mm profile ideal for low profile applications
- PCB footprint of 4mm²
- Low Gate Threshold Voltage
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

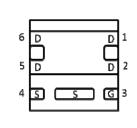
Mechanical Data

- Case: U-DFN2020-6 Type E
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.0065 grams (approximate)

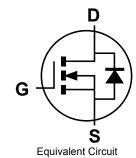


U-DFN2020-6 Type E

Bottom View



Pin Out



Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Quantity per reel
DMN4020LFDE-7	NE	7	3,000
DMN4020LFDE-7	NE	13	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



NE = Product Type Marking Code YM = Date Code Marking Y = Year (ex: A = 2013)

M = Month (ex: 9 = September)

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Year	201	1	2012	1	2013	20	14	2015	1	2016		2017
Teal	201	1	2012		2013	20	14	2010		2010	4	.017
Code	Y		Z		A	I	3	С		D		E
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	4	0	2		F	e	7	0	0	0	N	D

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40V N-CHANNEL ENHANCEMENT MODE MOSFET





DMN4020LFDE

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	40	V		
Gate-Source Voltage			V _{GSS}	±20	V
Ocationary Desig Compart (Nata C))/ - 40)/	Steady State	T _A = +25°C T _A = +70°C	۱ _D	8.0 6.3	А
Continuous Drain Current (Note 6) V_{GS} = 10V	T _A = +25°C T _A = +70°C	ID	9.5 7.5	А	
$O_{\text{continuous}} D_{\text{continuous}} O_{\text{continuous}} (h) = A_{\text{cont}} (h)$	ID	6.7 5.3	А		
Continuous Drain Current (Note 6) V_{GS} = 4.5V	t<10s	T _A = +25°C T _A = +70°C	ID	8.0 6.4	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	IDM	32	A		
Maximum Body Diode Continuous Current	Is	2.5	А		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Total Dawar Dissinction (Nata 5)	T _A = +25°C	D	0.66	W	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.42	vv	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	P	189	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ heta JA}$	132	C/VV	
Total Dower Dissinction (Note 6)	T _A = +25°C	Р	2.03	W	
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.31		
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	Р	61		
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ heta JA}$	43	°C/W	
Thermal Resistance, Junction to Case (Note 6)	$R_{ ext{ heta}JC}$	9.3			
Operating and Storage Temperature Range		T _{J.} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Min	Тур	Max	Unit	Test Condition
BV _{DSS}	40	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$
I _{DSS}	-	-	1	μA	$V_{DS} = 40V, V_{GS} = 0V$
I _{GSS}	-	-	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
V _{GS(th)}	1.4	-	2.4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Р		15	20	20	V _{GS} = 10V, I _D = 8A
RDS (ON)	-	20	28	11122	V_{GS} = 4.5V, I_{D} = 4A
V _{SD}	-	0.7	1	V	V _{GS} = 0V, I _S = 1A
Ciss	-	1060	-	pF	
Coss	-	84	-	pF	V _{DS} = 20V, V _{GS} = 0V, f = 1.0MHz
Crss	-	58	-	pF	1 - 1.00112
Rq	-	1.6	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Qg	-	8.8	-	nC	
Qg	-	19.1	-	nC	
Q _{gs}	-	3.0	-	nC	V _{DS} = 20V, I _D = 8A
Q _{qd}	-	2.5	-	nC	7
	-	5.3	-	ns	
tr	-	7.1	-	ns	$V_{DS} = 20V, R_{L} = 2.5\Omega$
t _{D(off)}	-	15.1	-	ns	V_{GS} = 10V, R_G = 3 Ω
t _f	-	4.8	-	ns	7
t _{rr}	-	10.5	-	ns	
	-	4.15	-	nC	−I _F = 8A, di/dt = 100A/μs
	$\begin{array}{c} BV_{DSS}\\ I_{DSS}\\ I_{GSS}\\ \end{array} \\ \hline \\ V_{GS(th)}\\ \hline \\ R_{DS (ON)}\\ \hline \\ V_{SD}\\ \hline \\ \hline \\ C_{iss}\\ \hline \\ C_{oss}\\ \hline \\ C_{rss}\\ \hline \\ R_{g}\\ \hline \\ Q_{g}\\ \hline \\ Q_{gs}\\ \hline \\ Q_{gd}\\ \hline \\ t_{D(on)}\\ \hline \\ t_{r}\\ \hline \\ t_{f}\\ \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

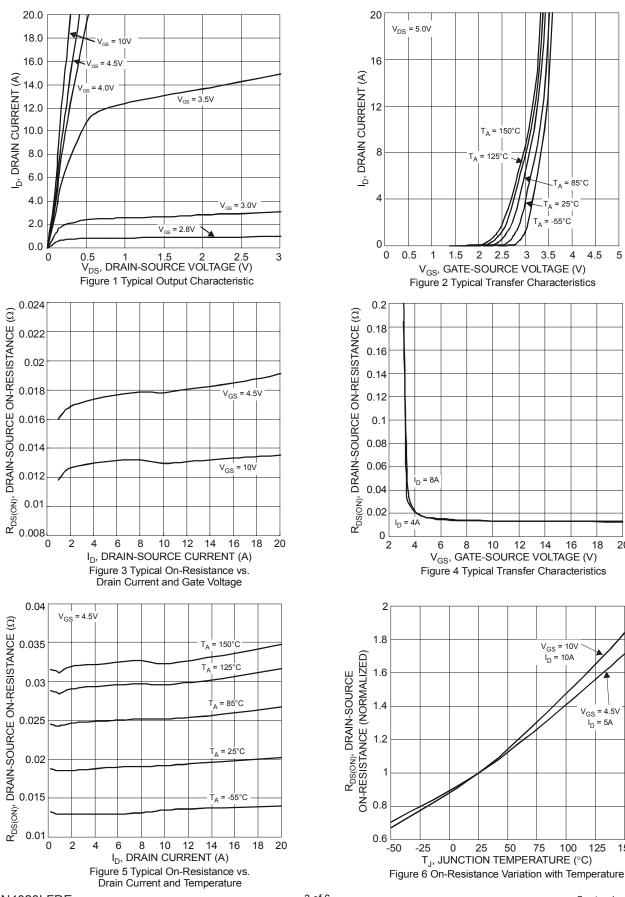
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate

7. Short duration pulse test used to minimize self-heating effect

8. Guaranteed by design. Not subject to production testing







DMN4020LFDE

= 85°C

= 25°C

4 4.5 5

-55°C

A

T_A = 150°C

125°C

2 2.5 3 3.5

8 10

25

50

75

100

125

12 14 16 18 20

V_{GS} = 4.5V I_D = 5A

V_{GS} = 10V I_D = 10A

DMN4020LFDE Datasheet number: DS35819 Rev. 3 - 2

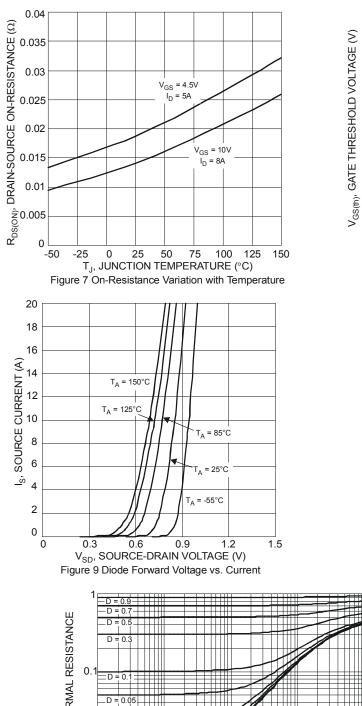
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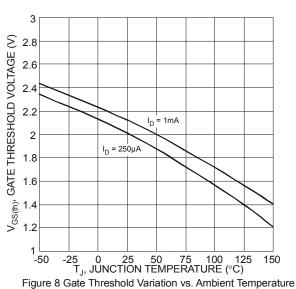
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DMN4020LFDE

r(t), TRANSIENT THERMAL RESISTANCE D 0.005 $R_{\theta JA}(t) = r(t) * R_{\theta JA}$ Single Pulse $R_{\theta JA} = 177^{\circ}C/W$ Duty Cycle, D = t1/ t2 0.001 100 0.0001 0.001 0.01 0.1 10 1000 1 t1, PULSE DURATION TIME (sec) Figure 13 Transient Thermal Resistance

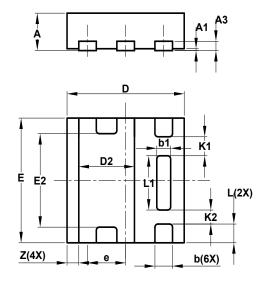
DMN4020LFDE Datasheet number: DS35819 Rev. 3 - 2





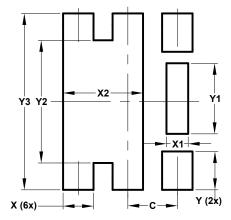
DMN4020LFDE

Package Outline Dimensions



U-DFN2020-6 Type E							
Dim	Min						
Α	0.57	0.63	0.60				
A1	0	0.05	0.03				
A3	_	I	0.15				
b	0.25	0.35	0.30				
b1	0.185	0.285	0.235				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
Е	1.95	2.05	2.00				
E2	1.40	1.60	1.50				
е	_	-	0.65				
L	0.25	0.35	0.30				
L1	0.82	0.92	0.87				
K1	_		0.305				
K2	_	_	0.225				
Z	_		0.20				
All	Dimens	ions in r	nm				

Suggested Pad Layout



Dimensions	Value (in mm)		
С	0.650		
Х	0.400		
X1	0.285		
X2	1.050		
Y	0.500		
Y1	0.920		
Y2	1.600		
Y3	2.300		





DMN4020LFDE

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